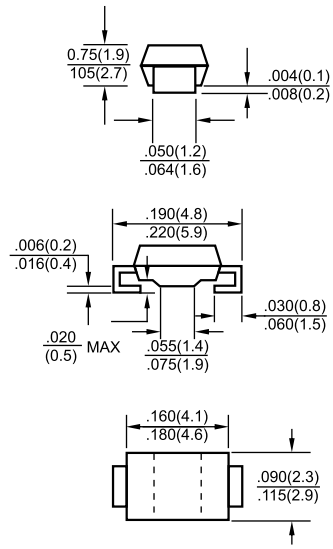
S1A-S1M

1.0AMP.Surface Mount Rectifiers

SMA/DO-214AC



Dimensions in inches and (millimeters)

Features

- ✧ For surface mounted application
- ✧ Glass passivated junction chip.
- ✧ Low forward voltage drop
- ✧ High current capability
- ✧ Easy pick and place
- ✧ High surge current capability
- ✧ Plastic material used carries Underwriters Laboratory Classification 94V-0
- ✧ High temperature soldering: 260°C / 10 seconds at terminals

Mechanical Data

- ✧ Case: Molded plastic
- ✧ Polarity: Indicated by cathode band
- ✧ Packaging: 12mm tape
- ✧ Weight: 0.064 gram

Maximum Ratings and Electrical Characteristics

Rating at 25 °C ambient temperature unless otherwise specified.
Single phase, half wave, 60 Hz, resistive or inductive load.
For capacitive load, derate current by 20%

Type Number	Symbol	S1A	S1B	S1D	S1G	S1J	S1K	S1M	Units
Maximum Recurrent Peak Reverse Voltage	V_{RRM}	50	100	200	400	600	800	1000	V
Maximum RMS Voltage	V_{RMS}	35	70	140	280	420	560	700	V
Maximum DC Blocking Voltage	V_{DC}	50	100	200	400	600	800	1000	V
Maximum Average Forward Rectified Current @T_L =110 °C	$I_{(AV)}$	1.0							A
Peak Forward Surge Current, 8.3 ms Single Half Sine-wave Superimposed on Rated Load (JEDEC method)	I_{FSM}	40						30	A
Maximum Instantaneous Forward Voltage @ 1.0A	V_F	1.1							V
Maximum DC Reverse Current @ T_A =25 °C at Rated DC Blocking Voltage @ T_A=125 °C	I_R	1.0 50							uA uA
Typical Reverse Recovery Time (Note 1)	Trr	1.5							uS
Typical Junction Capacitance (Note 2)	Cj	12							pF
Non-Repetitive Peak Reverse Avalanche Engergy at 25°C, I_{AS}=1A, L=10mH	E_{AS}	5							mJ
Typical Thermal Resistance (Note 3)	$R_{\theta JL}$ $R_{\theta JA}$	27 75					30 85		°C/W
Operating Temperature Range	T_J	-55 to +150							°C
Storage Temperature Range	TSTG	-55 to +150							°C

Notes: 1. Reverse Recovery Test Conditions: I_F=0.5A, I_R=1.0A, I_{RR}=0.25A
2. Measured at 1 MHz and Applied V_R=4.0 Volts
3. Measured on P.C. Board with 0.2" x 0.2" (5.0mm x 5.0mm) Copper Pad Areas.

S1A-S1M

1.0AMP.Surface Mount Rectifiers

RATINGS AND CHARACTERISTIC CURVES (S1A THRU S1M)

FIG.1- MAXIMUM FORWARD CURRENT DERATING CURVE

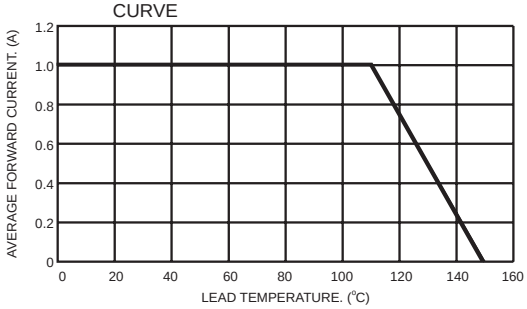


FIG.2- TYPICAL REVERSE CHARACTERISTICS

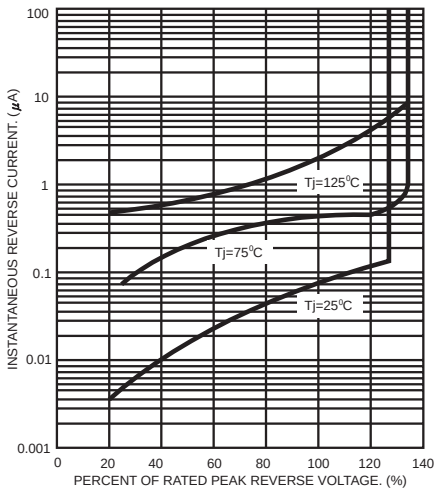


FIG.3- MAXIMUM NON-REPETITIVE FORWARD SURGE CURRENT

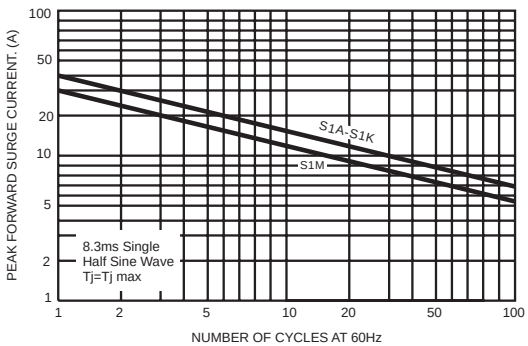


FIG.5- TYPICAL FORWARD CHARACTERISTICS

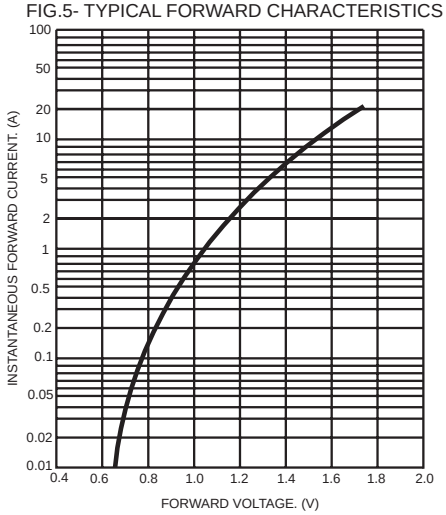


FIG.4- TYPICAL JUNCTION CAPACITANCE

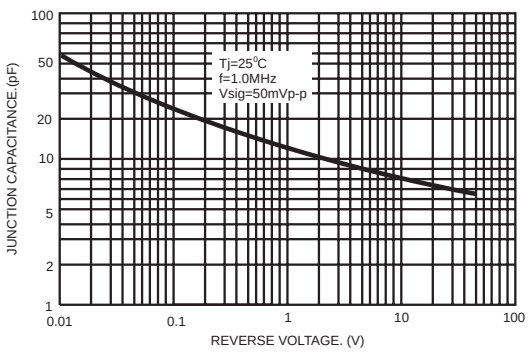
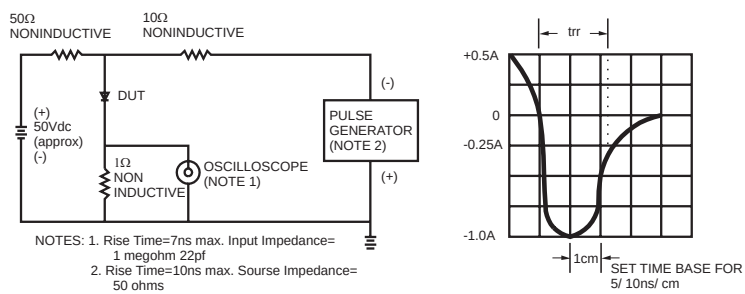


FIG.6- REVERSE RECOVERY TIME CHARACTERISTIC AND TEST CIRCUIT DIAGRAM



NOTES: 1. Rise Time=7ns max. Input Impedance= 1 megohm 22pf
2. Rise Time=10ns max. Sourse Impedance= 50 ohms

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